Supporting Information

Facile Synthesis of Single Crystalline Sub-micron Cu₂ZnSnS₄ (CZTS) Powders using Solvothermal Treatment

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Experimental

Fabrication of dye-sensitized solar cells (DSSCs)

The preparation of TiO₂ photoelectrodes were prepared from standard doctor blade technique using commercial TiO₂ paste (Dyesol 18NRT, Dyesol)) followed by annealing and dye loading (ethanolic 0.5 mM N719 dye solution (Dyesol)). The CZTS/FTO counter electrode (CE) was prepared by spin-coating. In a typical process, the asprepared CZTS powder were dispersed in 10 mL of ethyl alcohol and under ultra-sonication for 1 h to form a uniform 'ink' of CZTS. The 'ink' was then spin-coated onto a clean fluorine-doped tin oxide (FTO) glass substrate with a exposed area of 10×15 mm². The films were completely dried and then annealed at 100 °C in air. For comparison, Pt-coated FTO was used as a CE (purchased from Dyesol). DSSCs with an active area of 0.25 cm² were fabricated with a photoanode (a TiO₂ film sensitized by N719, Dyesol, Australia), a CE and an electrolyte containing 0.06 M LiI, 0.6 M 1-butyl-3-methylimidazoliumiodide, 0.03 M I₂, 0.5 M 4-tert-butyl pyridine and 0.1 M guanidinium thiocyanate in acetonitrile.



Figure S1 SEM images (a) (b) and EDS elemental map of CZTS particles (c) synthesized at 400 °C for 5h.



Table S1 Elemental ratios of the CZTS powders prepared at 400 °C for 5 h.

Figure S2 Raman spectra for the CZTS powders formed at 400 °C for 5 h, with the 325 nm He-Ne laser as the excitation source.

Method	Size distribution	а	b	c	Ref.
	/nm	(5.427 standard)/Å	(5.427 standard)/	(10.848 standard)/	
Solvothermal (400 °C,5h)	500-1000	5.430	5.430	10.828	Present work
Solvothermal (230 °C,24h)	~25	5.396	5.396	10.834	1
Microwave hydrothermal method (700W,10min)	10-100	5.420	5.420	10.848	2
Solvothermal (190 °C,24h)	~50	5.428	5.428	10.762	3
Solvothermal (180 °C,24h)	~5	5.400	5.400	10.800	4
Electrospinning with post annealing	100-150	5.440	5.440	10.890	5
Solvothermal (200 °C,16h)	150-300	5.431	5.431	10.826	6

Table S2 Comparison with the lattice parameters of CZTS using various synthesis methods.

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